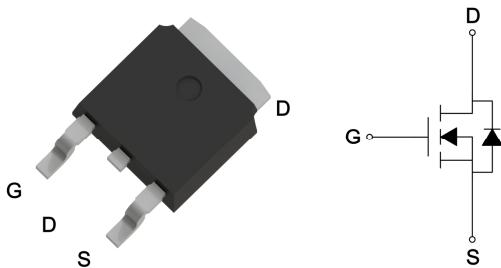


Product Summary

BV_{DSS}	200	V
$R_{DS(ON)}$ typ. @ $V_{GS}=10V$, $I_D=2A$	180	$m\Omega$
I_D @ $V_{GS}=10V$, $T_c=25^\circ C$	9	A
I_D @ $V_{GS}=10V$, $T_A=25^\circ C$	2.1	

TO-252



Ordering Information

Device	Package	Shipping
MTE180N20J3-0-T3-G	TO-252	2500pcs / Tape & Reel

0: Product rank, zero for no rank products.

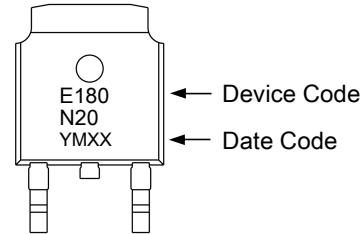
T3: Packing spec, T3 : 2500pcs / tape & reel, 13" reel

G: Environment friendly grade: S for RoHS compliant products, G for RoHS compliant and green compound products.

Features

- Low Gate Charge
- Fast Switching Characteristic
- Pb-free lead plating and halogen-free

Marking



YMXX: Date Code Marking

Y: Year Code, the last digit of Christian year

M: Month Code

A: Jan	B: Feb	C: Mar	D: Apr	E: May	F: Jun
G: Jul	H: Aug	J: Sep	K: Oct	L: Nov	M: Dec

XX: Production Serial Number, 01~99

Absolute Maximum Ratings ($T_A=25^\circ C$)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	200	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current @ $V_{GS}=10V$, $T_c=25^\circ C$	I_D	*a 9	
Continuous Drain Current @ $V_{GS}=10V$, $T_c=100^\circ C$		*a 5.7	
Continuous Drain Current @ $V_{GS}=10V$, $T_A=25^\circ C$		*b 2.1	
Continuous Drain Current @ $V_{GS}=10V$, $T_A=70^\circ C$		*b 1.7	
Pulsed Drain Current	I_{DM}	20	A
Continuous Body Diode Forward Current @ $T_c=25^\circ C$	I_S	9	
Pulsed Body Diode Forward Current @ $T_c=25^\circ C$	I_{SM}	20	
Avalanche Current @ $L=0.1mH$	I_{AS}	2	
Avalanche Energy @ $L=0.5mH$	E_{AS}	1.6	mJ
Total Power Dissipation	P_D	$T_c=25^\circ C$ *a 48	
		$T_c=100^\circ C$ *a 19	
		$T_A=25^\circ C$ *b 2.7	
		$T_A=70^\circ C$ *b 1.7	
Operating Junction and Storage Temperature Range	T_J , T_{stg}	-55~+150	°C
Steady State Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.6	°C/W
Steady State Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	46	

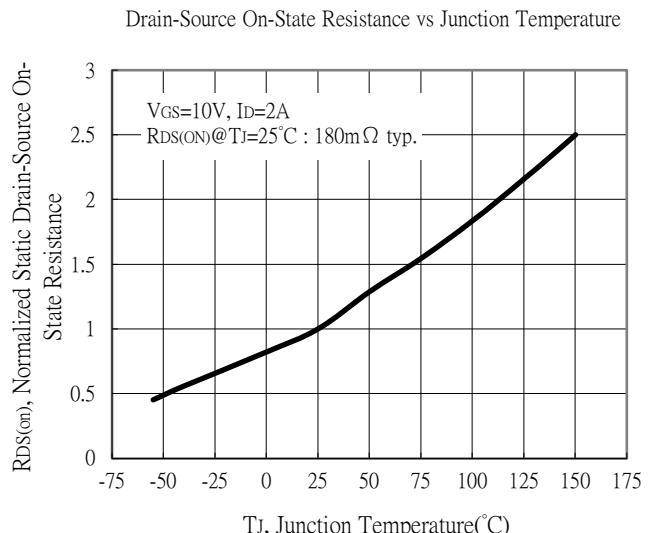
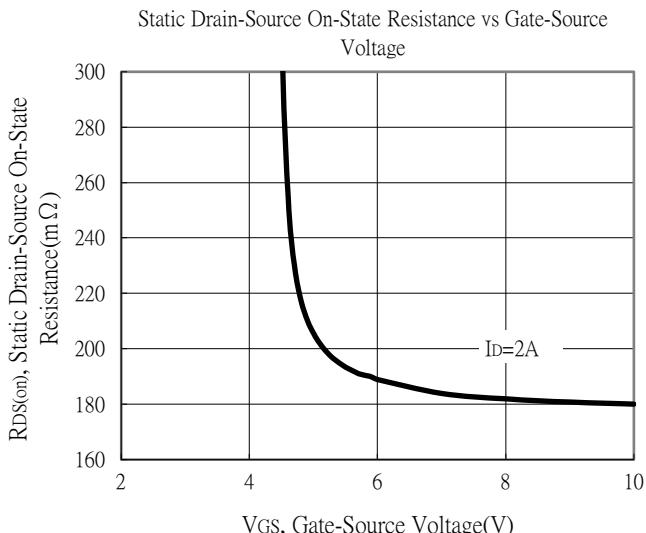
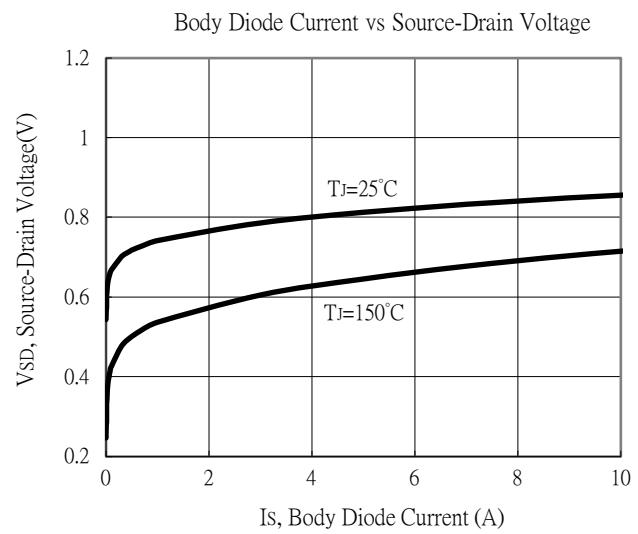
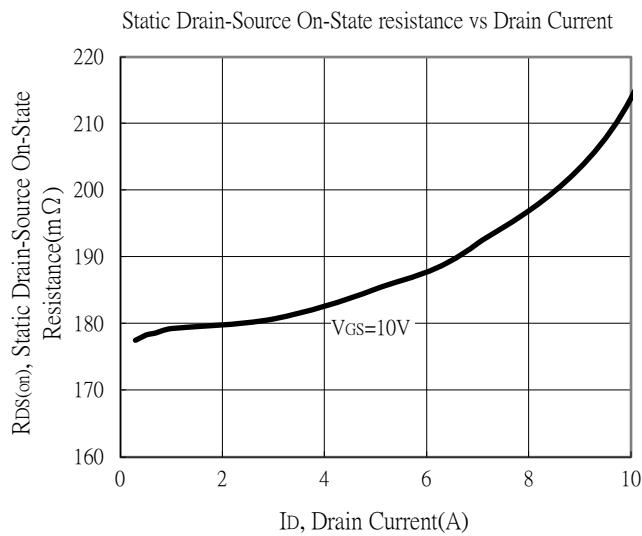
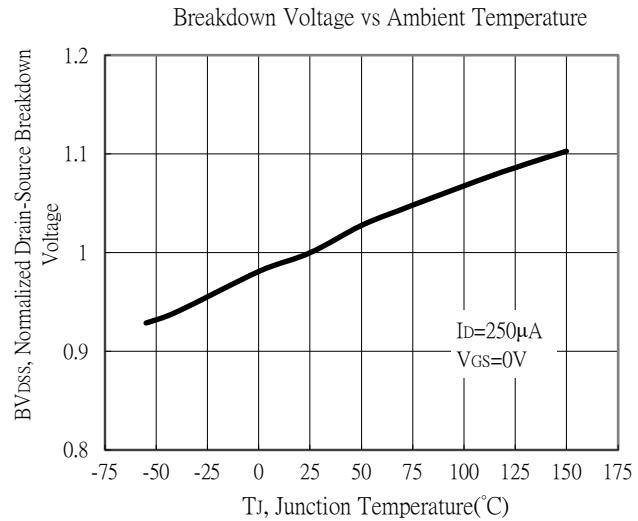
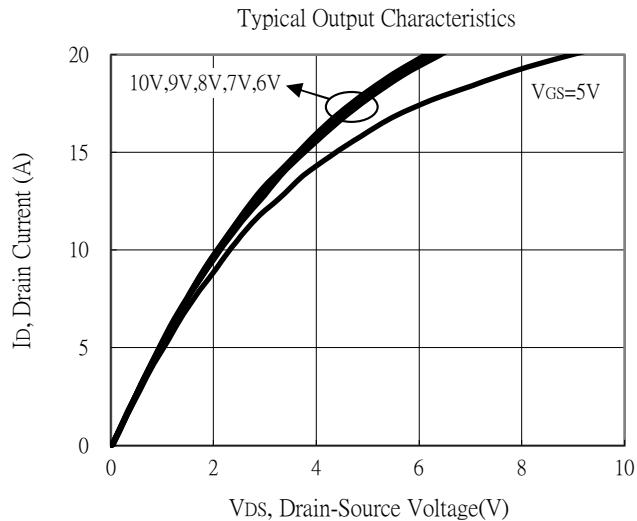
Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Static						
BV_{DSS}	200	-	-	V	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	
$\text{V}_{\text{GS}(\text{th})}$	2	-	4		$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	
G_{FS}	-	5	-	S	$\text{V}_{\text{DS}}=10\text{V}, \text{I}_D=2\text{A}$	
I_{GSS}	-	-	± 100	nA	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	
I_{DSS}	-	-	1	μA	$\text{V}_{\text{DS}}=160\text{V}, \text{V}_{\text{GS}}=0\text{V}$	
$\text{R}_{\text{DS}(\text{ON})}$	-	180	235	m Ω	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=2\text{A}$	
Dynamic						
C_{iss}	-	560	-	pF	$\text{V}_{\text{DS}}=100\text{V}, \text{V}_{\text{GS}}=0\text{V}, f=1\text{MHz}$	
C_{oss}	-	35	-			
C_{rss}	-	20	-	Ω	$f=1\text{MHz}$	
R_g	-	2	-			
$\text{Q}_{\text{g}} \text{ *d,e}$	-	14	-	nC	$\text{V}_{\text{DS}}=100\text{V}, \text{I}_D=2\text{A}, \text{V}_{\text{GS}}=10\text{V}$	
$\text{Q}_{\text{gs}} \text{ *d,e}$	-	2.6	-			
$\text{Q}_{\text{gd}} \text{ *d,e}$	-	4.1	-	ns	$\text{V}_{\text{DS}}=100\text{V}, \text{I}_D=2\text{A}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_{\text{GS}}=25\Omega$	
$\text{t}_{\text{d}(\text{ON})} \text{ *d,e}$	-	10	-			
$\text{tr} \text{ *d,e}$	-	18	-			
$\text{t}_{\text{d}(\text{OFF})} \text{ *d,e}$	-	30	-			
$\text{t}_f \text{ *d,e}$	-	37	-			
Source-Drain Diode						
$\text{V}_{\text{SD}} \text{ *d}$	-	0.79	1.2	V	$\text{I}_S=2\text{A}, \text{V}_{\text{GS}}=0\text{V}$	
t_{rr}	-	57	-	ns	$\text{I}_F=2\text{A}, \text{di}/\text{dt}=100\text{A}/\mu\text{s}$	
Q_{rr}	-	102	-	nC		

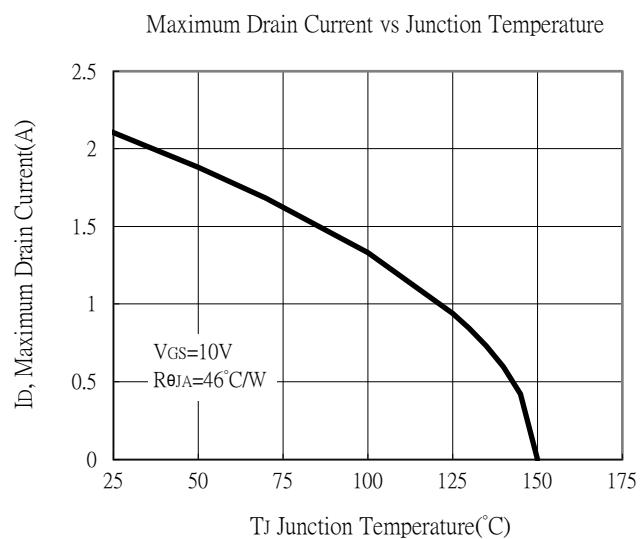
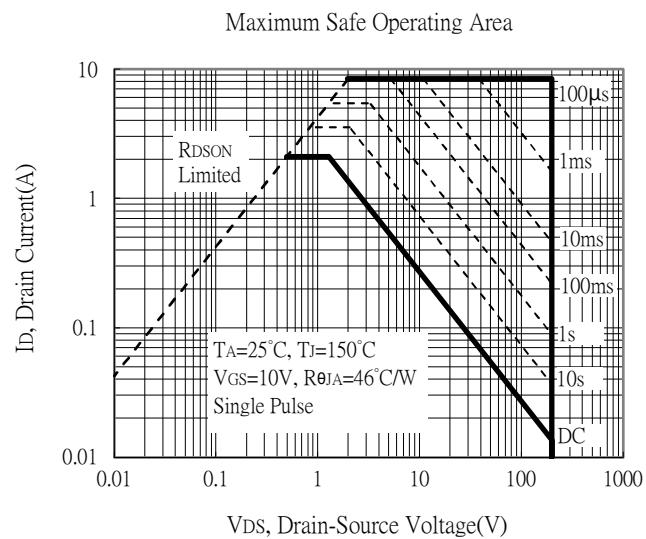
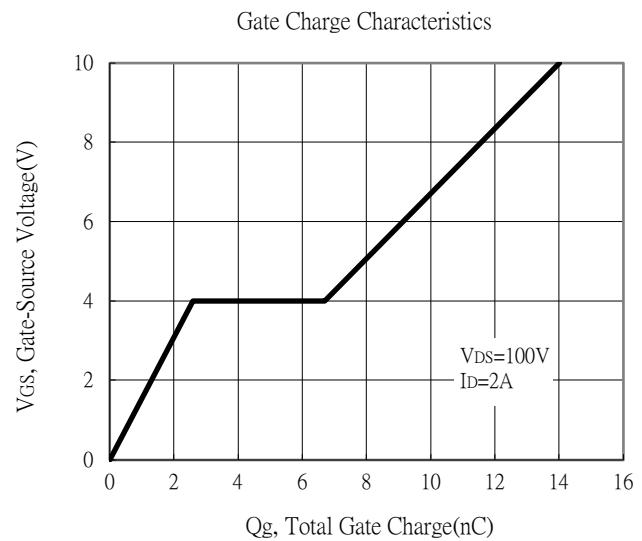
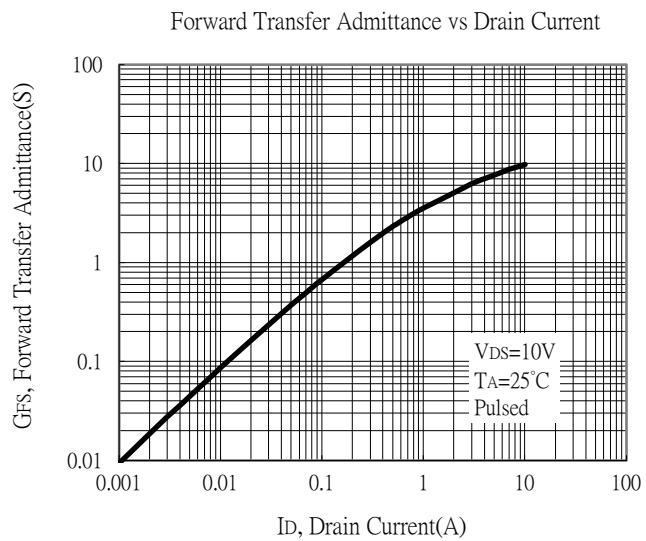
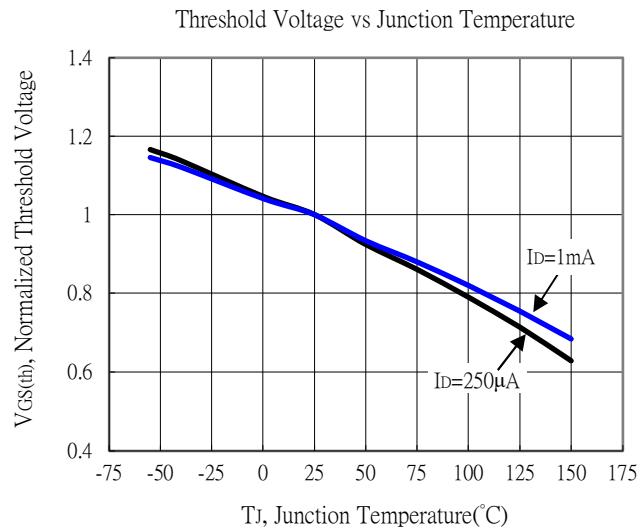
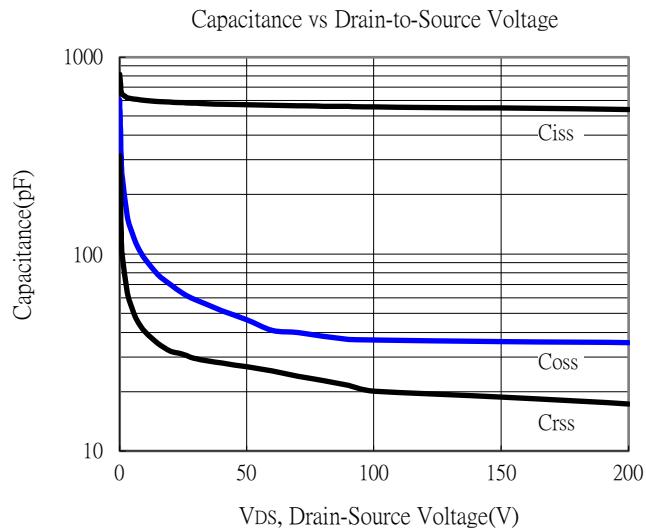
Note:

- *a. The power dissipation P_D is based on $T_{J(\text{MAX})}=150^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper Dissipation.
- *b. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz copper, in a still air environment with $T_A=25^\circ\text{C}$. The power dissipation P_D is based on $R_{\theta JA}$ and the maximum allowed junction temperature of 150°C . The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature $T_{J(\text{MAX})}=150^\circ\text{C}$. Ratings are based on low frequency and low duty cycles to keep initial $T_J=25^\circ\text{C}$.
- *d. Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- *e. Independent of operating temperature.

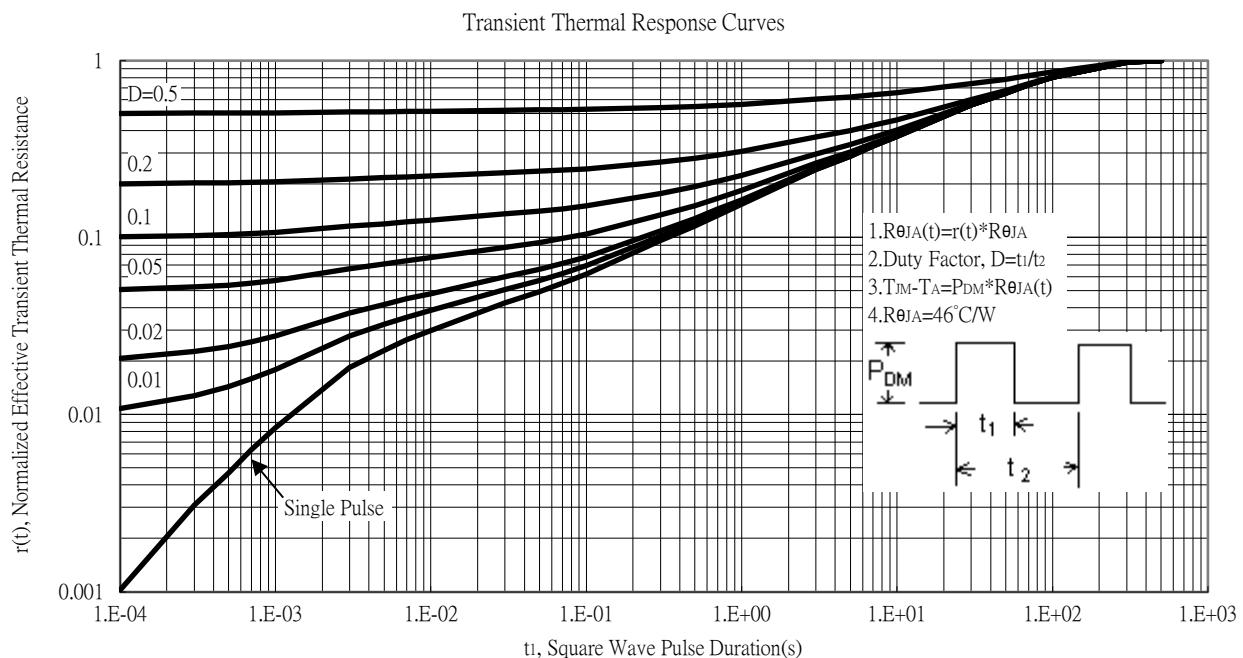
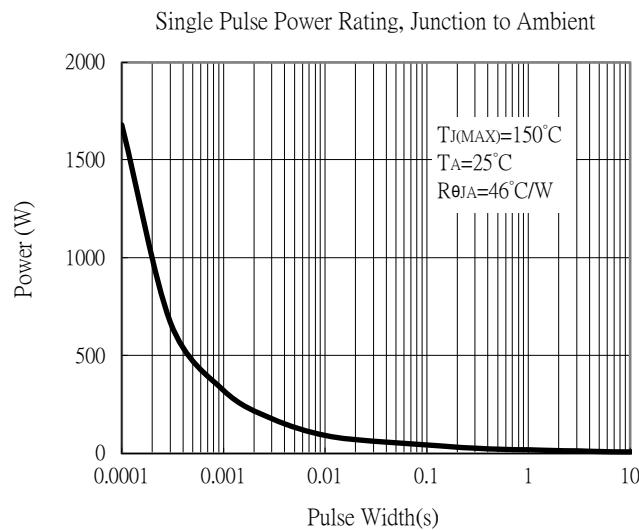
Typical Characteristics



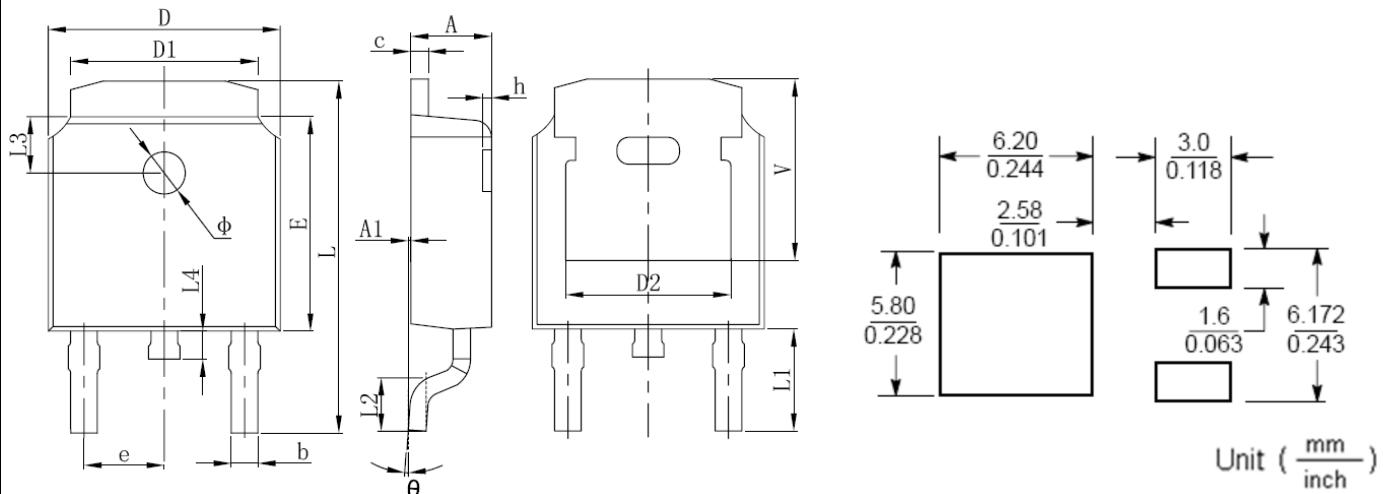
Typical Characteristics



Typical Characteristics



TO-252 Dimension



3-Lead TO-252 Plastic Surface Mount Package
CYS Package Code: J3

Recommended Soldering Footprint

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	L	0.382	0.406	9.712	10.312
A1	0.000	0.005	0.000	0.127	L1	0.114	REF	2.900	REF
b	0.025	0.030	0.635	0.770	L2	0.055	0.067	1.400	1.700
c	0.018	0.023	0.460	0.580	L3	0.63	REF	1.600	REF
D	0.256	0.264	6.500	6.700	L4	0.024	0.039	0.600	1.000
D1	0.201	0.215	5.100	5.460	Φ	0.043	0.051	1.100	1.300
D2	0.190	REF	4.830	REF	θ	0°	8°	0°	8°
E	0.236	0.244	6.000	6.200	h	0.000	0.012	0.000	0.300
e	0.086	0.094	2.186	2.386	V	0.207	REF	5.250	REF

Note:

- Controlling dimension: millimeters.
- Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
- If there is any question with packing specification or packing method, please contact your local CYStek sales office.

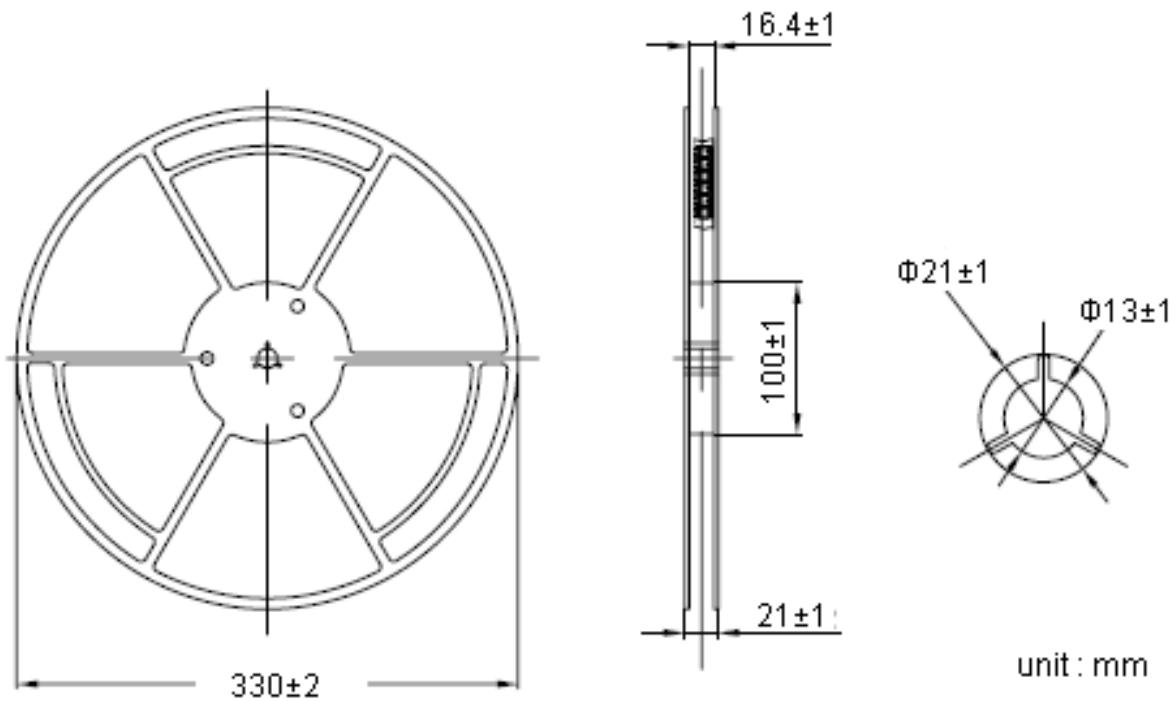
Material:

- Lead: pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

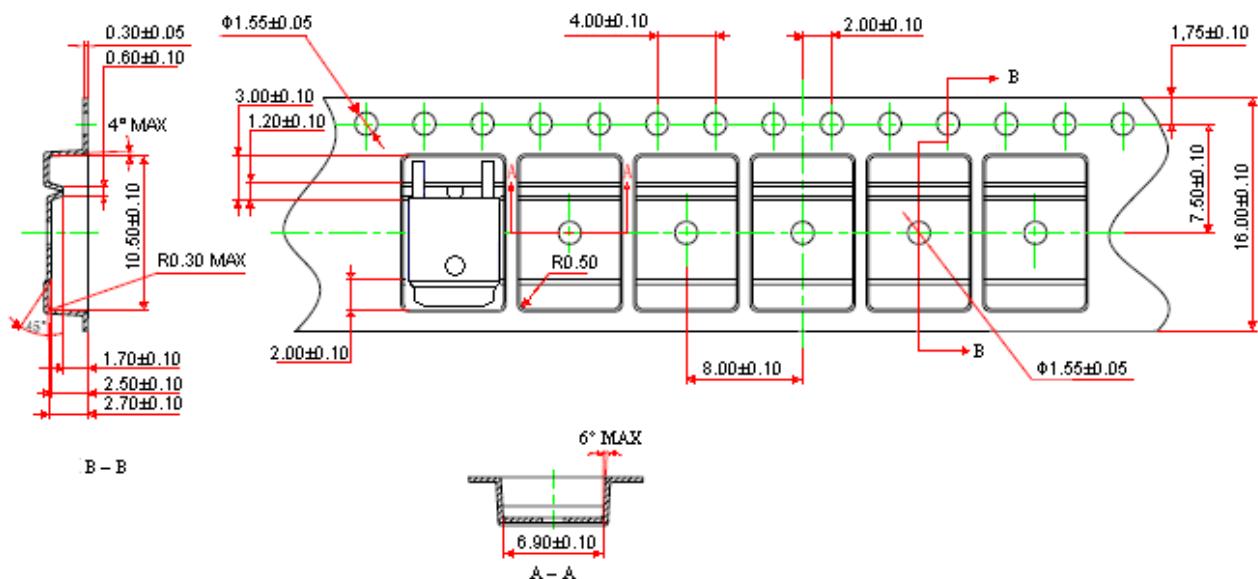
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Reel Dimension



Carrier Tape Dimension



Notes:

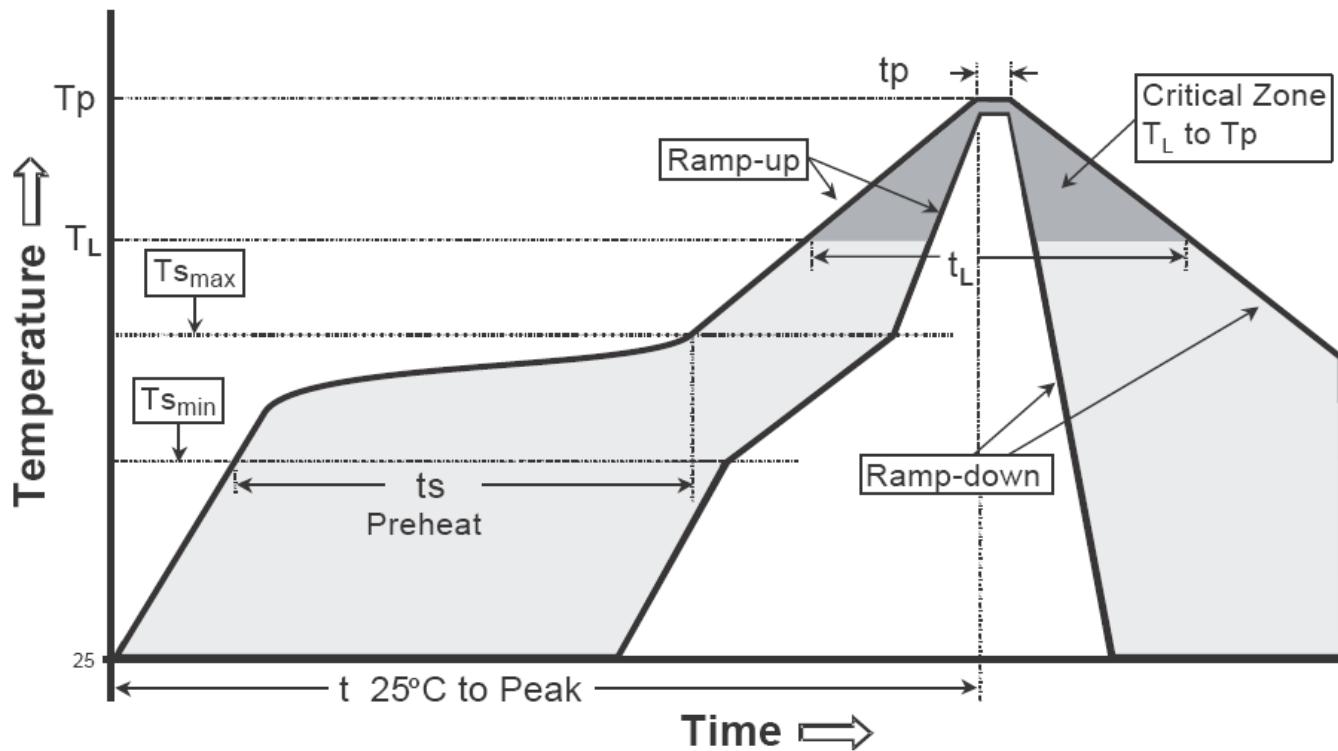
1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material: conductive black polystyrene, antistatic coated : $10^5 \Omega/\square \sim 10^{11} \Omega/\square$

unit : mm

Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T_s min to T_p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min (T_s min) -Temperature Max (T_s max) -Time (t_s min to t_s max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T_L) -Time (t_L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature (T_p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature (t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note:

- All temperatures refer to topside of the package, measured on the package body surface.